FHR170RM

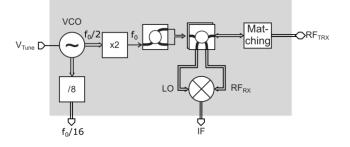
D-Band FMCW Radar MMIC



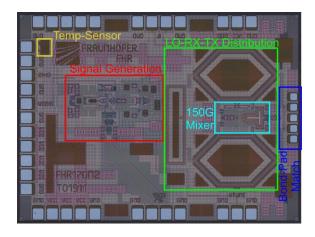
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Block Diagram



Microphotograph



Further Reading

S. Hansen, C. Bredendiek, G. Briese, A. Froehly, R. Herschel and N. Pohl, "A SiGe-Chip-Based D-Band FMCW-Radar Sensor With 53-GHz Tuning Range for High Resolution Measurements in Industrial Applications," in *IEEE Transactions on Microwave Theory and Techniques*, vol. 70, no. 1, pp. 719-731, Jan. 2022, doi: 10.1109/TMTT.2021.3121746.

Description

FHR170RM is a large bandwidth frequency modulated continuous wave (FMCW) monolithic microwave integrated circuit (MMIC) intended for high precision monostatic D-Band radar modules. The chip features a voltage controlled oscillator (VCO) that can be modulated by an external phased locked loop via the frequency divided output signal. The received signal is downconverted by an integrated direct down conversion gilbert cell mixer. The MMIC has been successfully evaluated in a D-Band radar sensor achieving a range resolution of 3.3 mm.

Specifications

Technology	Infineon B11HFC, SiGe-BiCMOS
Center Frequency [GHz]	148
Bandwidth [GHz]	56
Architecture	monostatic
Channels	1 TRX
P _{out,MMIC} [dBm]	-7
P _{DC,MMIC} [mW]	340
Dimension [µm]	1964 x 1448

Tuning Curve and Phase Noise

